

# Nch 250V 10A Power MOSFET

$V_{DSS}$	250V
R <sub>DS(on)</sub> (Max.)	320m $Ω$
I <sub>D</sub>	10A
$P_D$	85W

# Features

- 1) Low on-resistance.
- 2) Fast switching speed.
- 3) Drive circuits can be simple.
- 4) Parallel use is easy.
- 5) Pb-free lead plating; RoHS compliant
- 6) 100% Avalanche tested

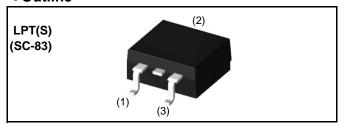
# Application

**Switching Power Supply** 

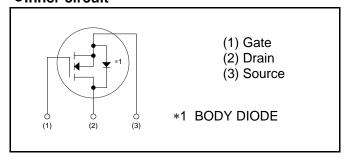
**Automotive Motor Drive** 

Automotive Solenoid Drive

## Outline



# •Inner circuit



Packaging specifications

	Packaging	Taping
	Reel size (mm)	330
Type	Tape width (mm)	24
Туре	Basic ordering unit (pcs)	1,000
	Taping code	TL
	Marking	RCJ100N25

# ● Absolute maximum ratings(T<sub>a</sub> = 25°C)

Paramete	Symbol	Value	Unit	
Drain - Source voltage	V <sub>DSS</sub>	250	V	
Continuous design surrent	T <sub>c</sub> = 25°C	I <sub>D</sub> *1	±10	А
Continuous drain current	T <sub>c</sub> = 100°C	I <sub>D</sub> *1	±5.4	А
Pulsed drain current	I <sub>D,pulse</sub> *2	±40	А	
Gate - Source voltage	V <sub>GSS</sub>	±30	V	
Avalanche energy, single puls	е	E <sub>AS</sub> *3	7.29	mJ
Avalanche current		I <sub>AR</sub> *3	5.0	А
$T_c = 25$ °C		P <sub>D</sub>	85	W
Power dissipation $T_a = 25^{\circ}C^{*4}$		P <sub>D</sub>	1.56	W
Junction temperature		T <sub>j</sub>	150	°C
Range of storage temperature		T <sub>stg</sub>	-55 to +150	°C

# ●Thermal resistance

Parameter	Symbol	Values			Unit
- Farameter	Symbol	Min.	Тур.	Max.	Offic
Thermal resistance, junction - case	$R_{thJC}$	-	-	1.46	°C/W
Thermal resistance, junction - ambient *4	$R_{thJA}$	-	-	80	°C/W
Soldering temperature, wavesoldering for 10s	$T_{sold}$	-	-	265	°C

# •Electrical characteristics( $T_a = 25$ °C)

Parameter	Symbol	Conditions		Values	Unit	
Farameter	Symbol	Conditions	Min.	Тур.	Max.	Offic
Drain - Source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0V$ , $I_D = 1mA$	250	-	-	V
Zero gate voltage drain current	I <sub>DSS</sub>	$V_{DS} = 250V, V_{GS} = 0V$ $T_j = 25^{\circ}C$	ı	1	10	μΑ
Gate - Source leakage current	$I_{GSS}$	$V_{GS} = \pm 30V, V_{DS} = 0V$	1	-	±100	nA
Gate threshold voltage	V <sub>GS (th)</sub>	$V_{DS} = 10V$ , $I_D = 1mA$	3.0	-	5.0	V
		$V_{GS} = 10V, I_D = 5.0A$	-	245	320	
Static drain - source on - state resistance	R <sub>DS(on)</sub> *5	$V_{GS} = 10V, I_D = 5.0A$ $T_j = 125^{\circ}C$		520	730	mΩ
Forward transfer admittance	<b>g</b> fs	$V_{DS} = 10V, I_{D} = 5.0A$	2.7	5.4	-	S

# ●Electrical characteristics(T<sub>a</sub> = 25°C)

Parameter	Symbol	Conditions		Unit		
r ai ai ii e lei	Syllibol	Conditions	Min.	Тур.	Max.	Offic
Input capacitance	$C_{iss}$	$V_{GS} = 0V$	-	1440	-	
Output capacitance	C <sub>oss</sub>	V <sub>DS</sub> = 25V	-	75	-	pF
Reverse transfer capacitance	$C_{rss}$	f = 1MHz	-	40	-	
Turn - on delay time	t <sub>d(on)</sub> *5	$V_{DD} \simeq 125V, V_{GS} = 10V$	-	29	-	
Rise time	t <sub>r</sub> *5	$I_{D} = 5.0A$	-	40	-	nc
Turn - off delay time	t <sub>d(off)</sub> *5	$R_L = 24.9\Omega$	-	40	-	ns
Fall time	t <sub>f</sub> *5	$R_G = 10\Omega$	-	16	-	

# • Gate Charge characteristics ( $T_a = 25$ °C)

Parameter	Cymbol	Values		Unit		
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Offic
Total gate charge	$Q_g^{*5}$	V <sub>DD</sub> ≃ 125V	-	26.5	-	
Gate - Source charge	Q <sub>gs</sub> *5	I <sub>D</sub> = 10A	-	10.25	-	nC
Gate - Drain charge	Q <sub>gd</sub> *5	V <sub>GS</sub> = 10V	-	9.8	-	
Gate plateau voltage	V <sub>(plateau)</sub>	$V_{DD} \simeq 125V, I_D = 10A$	-	7.3	-	V

# ●Body diode electrical characteristics (Source-Drain)(T<sub>a</sub> = 25°C)

Parameter	Symbol	Conditions			Values	
Parameter	Symbol Conditions -		Min.	Тур.	Max.	Unit
Continuous source current	I <sub>S</sub> *1	T <sub>c</sub> = 25°C	-	1	10	Α
Pulsed source current	I <sub>SM</sub> *2	1 <sub>c</sub> = 23 0	-	-	40	Α
Forward voltage	V <sub>SD</sub> *5	$V_{GS} = 0V, I_{S} = 10A$	-	-	1.5	V
Reverse recovery time	t <sub>rr</sub> *5	I <sub>S</sub> = 5.0A	-	105	-	ns
Reverse recovery charge	Q <sub>rr</sub> *5	di/dt = 100A/μs	-	370	-	nC

<sup>\*1</sup> Limited only by maximum temperature allowed.

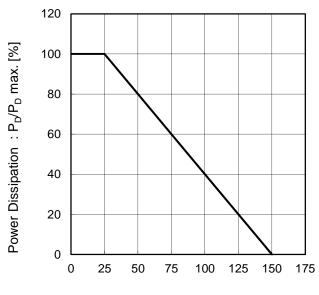
\*5 Pulsed

<sup>\*2</sup> Pw  $\leq$  10 $\mu$ s, Duty cycle  $\leq$  1%

<sup>\*3</sup> L  $^{\simeq}$  500 $\mu$ H, V<sub>DD</sub> = 50V, Rg = 25 $\Omega$ , starting T $_{j}$  = 25°C

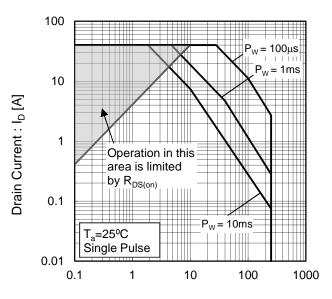
<sup>\*4</sup> Mounted on a epoxy PCB FR4 (25mm × 27mm × 0.8mm)

Fig.1 Power Dissipation Derating Curve



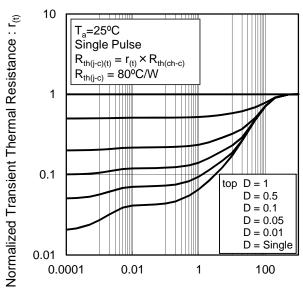
Junction Temperature : T<sub>i</sub> [°C]

Fig.2 Maximum Safe Operating Area



Drain - Source Voltage : V<sub>DS</sub> [V]

Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width



Pulse Width :  $P_W[s]$ 

Fig.4 Avalanche Current vs Inductive Load

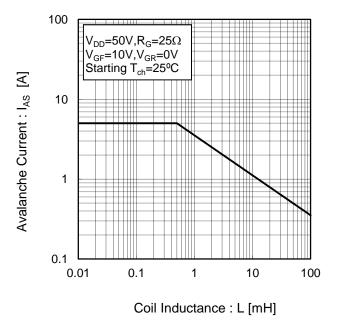
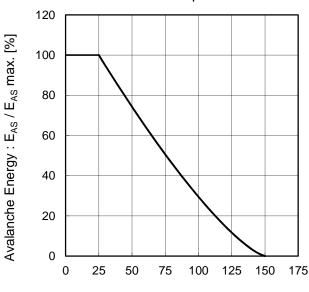


Fig.5 Avalanche Energy Derating Curve vs Junction Temperature



Junction Temperature : T<sub>i</sub> [°C]

Fig.6 Typical Output Characteristics(I)

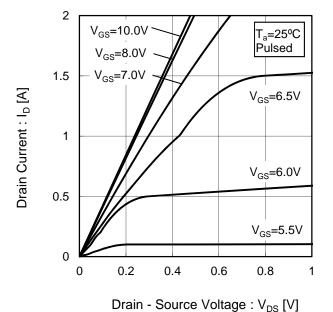
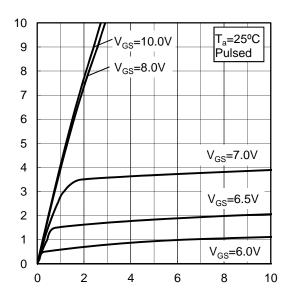


Fig.7 Typical Output Characteristics(II)



Drain - Source Voltage : V<sub>DS</sub> [V]

Drain Current : I<sub>D</sub> [A]

Fig.8 Breakdown Voltage vs. Junction Temperature 340 Normarize Drain - Source Breakdown Voltage  $V_{GS} = 0V$  $I_D = 1 \text{mA}$ 320 300  $: V_{(BR)DSS}[V]$ 280 260 240 220 -50 0 50 100 150 Junction Temperature : T<sub>i</sub> [°C]

Fig.9 Typical Transfer Characteristics 100  $V_{DS} = 10V$ 10

Drain Current: I<sub>D</sub> [A] 0.1 T<sub>a</sub>= 125°C T<sub>a</sub>= 75°C  $T_{a}^{a} = 25^{\circ}C$ 0.01  $T_a = -25^{\circ}C$ 0.001 0 2 3 4 5 8 9

Gate - Source Voltage : V<sub>GS</sub> [V]

Fig.10 Gate Threshold Voltage vs. Junction Temperature

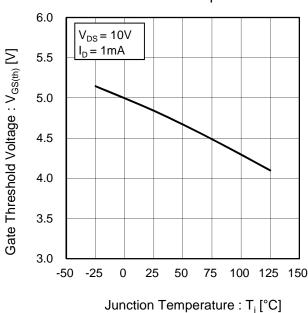
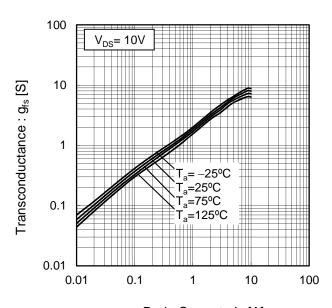


Fig.11 Transconductance vs. Drain Current



Drain Current : I<sub>D</sub> [A]

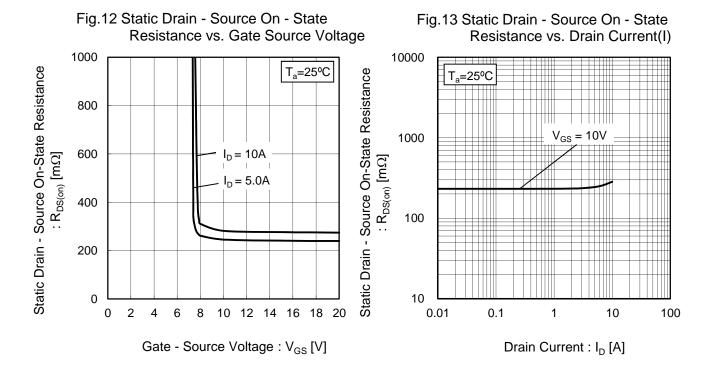


Fig.14 Static Drain - Source On - State Resistance vs. Junction Temperature

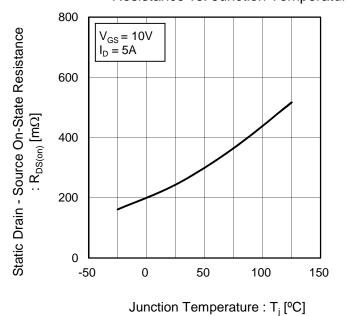


Fig.15 Static Drain - Source On - State Resistance vs. Drain Current(II)

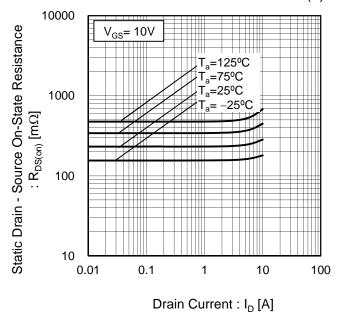


Fig.16 Drain Current Derating Curve

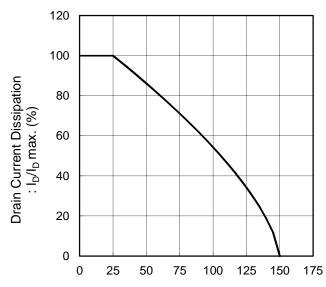
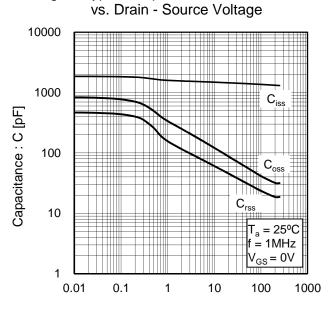
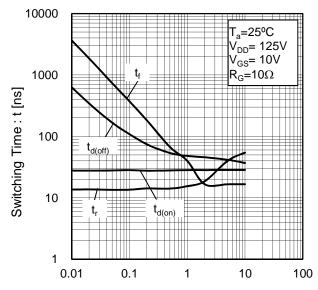


Fig.17 Typical Capacitance



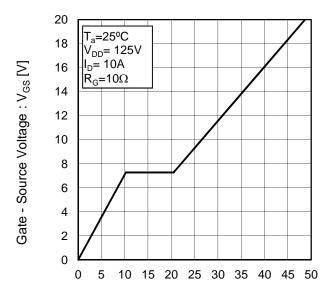
Drain - Source Voltage : V<sub>DS</sub> [V]

Fig.18 Switching Characteristics

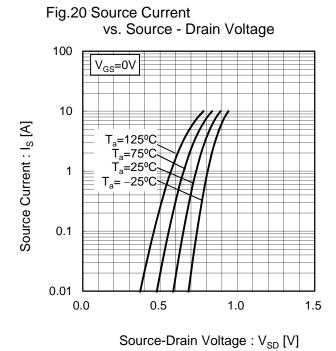


Drain Current : I<sub>D</sub> [A]

Fig.19 Dynamic Input Characteristics



Total Gate Charge :  $Q_g$  [nC]



Vs. Source Current

1000

1000

1000

1000

T<sub>a</sub>=25°C

di / dt = 100A / μs

V<sub>GS</sub> = 0V

0.1 1 10 100

Source Current : I<sub>S</sub> [A]

Fig21 Reverse Recovery Time

# ●Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

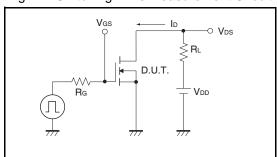


Fig.2-1 Gate Charge Measurement Circuit

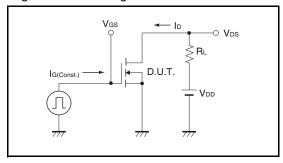


Fig.3-1 Avalanche Measurement Circuit

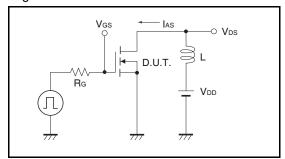


Fig.1-2 Switching Waveforms

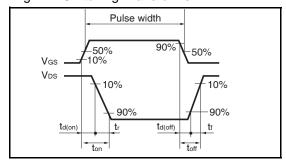


Fig.2-2 Gate Charge Waveform

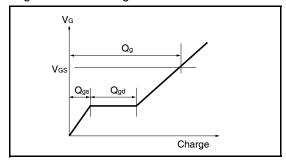
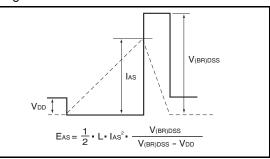
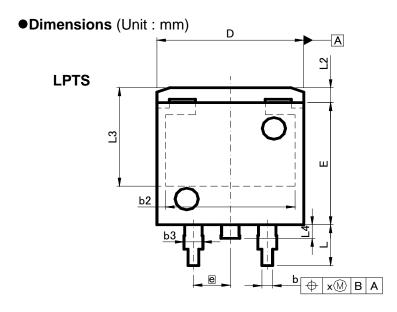
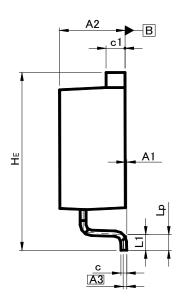
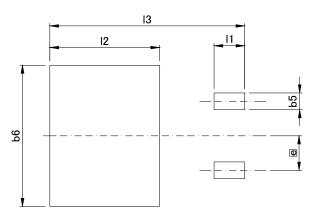


Fig.3-2 Avalanche Waveform









# Patterm of terminal position areas

DIM	MILIMETERS		INC	HES	
DIM	MIN	MAX	MIN	MAX	
A1	0.00	0.30	0	0.012	
A2	4.30	4.70	0.169	0.185	
A3	0.:	25	0.	01	
b	0.68	0.98	0.027	0.039	
b2	8.	90	0.	35	
b3	1.14	1.44	0.045	0.057	
С	0.30	0.60	0.012	0.024	
c1	1.10	1.50	0.043	0.059	
D	9.80	10.40	0.386	0.409	
E	8.80	9.20	0.346	0.362	
е	2.	54	0.10		
HE	12.80	13.40	0.504	0.528	
L	2.70	3.30	0.106	0.13	
L1	0.90	1.50	0.035	0.059	
L2	1.	10	0.0	)43	
L3	7.25		0.285		
L4	1.	00	0.0	39	
Lp	0.90	1.50	0.035	0.059	
Х	_	0.25	_	0.01	

DIM	MILIM	ETERS	INC	HES
DIIVI	MIN	MAX	MIN	MAX
b5	ı	1.23	ı	0.049
b6	İ	10.40	İ	0.409
11	-	2.10	-	0.083
12	=	7.55	-	0.297
13	_	13.40	_	0.528

Dimension in mm/inches

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- 4. The Products are not subject to radiation-proof design.
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- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
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  - [d] the Products are exposed to high Electrostatic
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